



SPN02N60S5 Information



For Reference Only

Part Number SPN02N60S5

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 600V 0.4A SOT-223

Package TO-261-4, TO-261AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SPN02N60S5 Specifications

Manufacturer Part Number	SPN02N60S5
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-261-4, TO-261AA
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	400mA (Ta)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5.5V @ 80μA
Gate Charge (Qg) (Max) @ Vgs	7.4nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	250pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	1.8W (Ta)
Rds On (Max) @ Id, Vgs	3 Ohm @ 1.1A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-SOT223-4
Package / Case	TO-261-4, TO-261AA
	Report errors?

SPN02N60S5 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SPN02N60S5 Payment Methods



















SPN02N60S5 Shipping Methods













If you have any question about SPN02N60S5, please do not hesitate to contact us!

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